NSN 5962-01-185-9619

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Deskal	
Body L	-
1.290 in	
Body W	
	n 0.500 inches and 0.610 inches
Body H	
0.210 in	
	Im Power Dissipation Rating:
1.02 wa	
	ng Tempurature Range:
	25.0 degrees celsius
	e Tempurature Range:
	50.0 degrees celsius
	plication:
	ystem an/fps-117
	es Provided:
	cally sealed and monolithic and bipolar and programmable and schottky
	re Material:
	c and glass
Inclosu	re Configuration:
Dual-in-	line
Output	Logic Form:
Transist	or-transistor logic
nput C	ircuit Pattern:
14 input	
Case O	utline Source And Designator:
D-3 mil-	m-38510
Termin	al Surface Treatment:
Solder	
Voltage	Rating And Type Per Characteristic:
5.5 volts	s power source
Time R	ating Per Chacteristic:
100.00	nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level
output	
Memor	y Device Type:
Rom	
Memory	y Capacity:
Unknow	'n
Termin	al Type And Quantity:
5 printe	d circuit
Shelf Li	ife:
N/a	
Unit Of	Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

